

Infrared Emitter

Prodeuct No: HSE1750-L504

FEATURES

- > High Power Infrared LED
- > Peak wavelength typ. 1550 nm
- > Very High radiant Intensity
- > Emission angle ±4°

SAFETY ADVICES

Depending on the application, these devices which emit infrared light may exceed over Accessible Emission Limit and cause the damage to the human eye. Keep the safety precautions given in IEC 60825-1 and IEC 625471 before using.

Absolute Maximum Ratings (Ta=25°C)

Items	Symbol Maximum Rated Value		Unit	Pb Ro
Power Dissipation	Pd	120	mW	
Forward Current	lf	100	mA	
Pulse Forward Current	lfp	1000	mA	
Reverse Voltage	Vr	5	V	
Thermal Resistance	Rthja		K/W	
Junction Temperature	Tj		°C	
Operating Temperature	Topr	-40 ~ +85	°C	
Storage Temperature	Tstg	-40 ~ +100	°C	
Soldering Temperature	Tsol	265	°C	

APPLICATIONS

> Light Sources for analysis> Industrial Light Sources

‡Pulse Forward Current condition: Duty=1% and Pulse Width=10us.
‡Soldering condition: Soldering condition must be completed within 3 seconds at 265°C
‡Termal resistance: junction – ambient, leads 7mm, soldered on PCB.

Electrical & Optical Characteristics (Ta=25°C)										
ITEMS	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNIT				
Forward Voltage	Vf	IF=20mA		1.0	1.5	V				
Reverse Current	IR	VR=5V			10	uA				
Radiated Power	Po	IF=20mA	0.5	1.5		mW				
Radiant Intensity	ΙE	IF=20mA		32		mW/sr				
Peak Wavelength	λP	IF=20mA	1700	1750	1800	nm				
Half Width	$\Delta \lambda$	IF=20mA		70		l 🗌 n.m				
Dominant Wavelength	λD	IF=20mA				nm				
Viewing Half Angle	01/2	IF=20mA		±4		deg				
Rise Time / Fall Time	Tr/tf	IF=20mA		10/10		ns				

‡Radiated Power is measured by S8370-85.

‡Radiant Intensity is measured by Tektronix J-6512.

TEL:400-008-2928 18688757161 QQ:1622377954

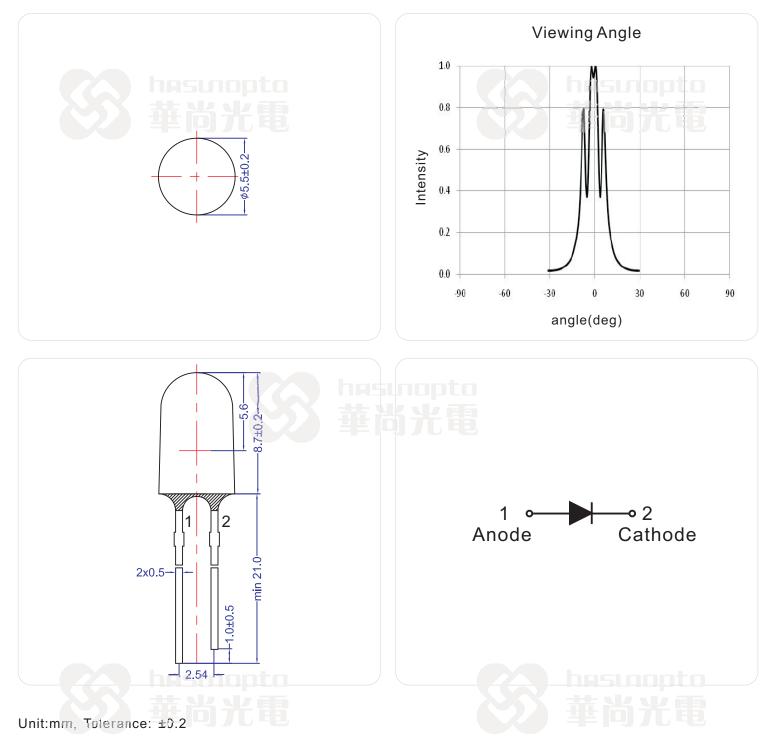




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Dimension of LED Lamp



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